

SPECIFICAȚII TEHNICE Anexa 22

Numărul licitației:	ocds-b3wdp1-MD-1715688302478	23.05.2024	Alternativa nr.-
Denumire a licitației:	Piese si dispozitive pentru computere	Lot: 1-2-4	Pagina 1 din 1
Centrul de Tehnologii Informationale in Finante			

Nr d/o	cod CPV	Denumirea bunurilor și/sau a serviciilor	Modelul articolului	Țara de origine	Produ-cătorul	Specificarea tehnică deplină solicitată	Specificarea tehnică deplină propusă de către ofertant	Standarde de referință
1		2	3	4	5	6	7	8

Lotul 1 Memorie Operativa

1,1	30237000-9	Memorie operativă DDR3	GR1600D3V64L11/8G	China	GOODRAM	DDR3 8Gb mîim: 1600mhz	GR1600D3V64L11/8G 8GB DDR3L-1600 GOODRAM, PC12800, CL11, 1.35V	
1,2		Memorie oerativă DDR4	GR2666D464L19S/8G	China	GOODRAM	DDR4 8Gb minim: 2666mhz	GR2666D464L19S/8G 8GB DDR4-2666 GOODRAM, PC21300, CL19, 1024x8, 1.2VV	
1,3		Memorie operativă SODIMM	PSD38G16002S	China	PATRIOT	DDR3 8Gb minim 1600nhz	PSD38G16002S 8GB DDR3-1600 SODIMM PATRIOT Signature Line, PC12800, CL11, 2 Rank, Double-sided module, 1.5V	

Lot 2 Dispozitive de stocare (SSD)

2,1	30237000-9	SSD 250 Gb	SSD 250 GB Samsung SSD 870 EVO	China	Samsung	250GB 2.5, SATA III R7w:560/530MB/s, 98K IoPs, MGx, V-NAND 3bit MLC	2.5" SSD 250GB Samsung SSD 870 EVO, SATAIII, Sequential Reads: 560 MB/s, Sequential Writes: 530 MB/s, Max Random 4k: Read: 98,000 IOPS / Write: 88,000 IOPS, 7mm, 512MB Cache, Samsung MKX controller, V-NAND 3bit MLC	
2,2		SSD 500 Gb	SSD 500GB Samsung SSD 870 EVO	China	Samsung	500Gb 2,5" SATA III R./W:s 560/530 MB/s, 98K IOPS, MGx, V-NAND 3bit MLC	2.5" SSD 500GB Samsung SSD 870 EVO, SATAIII, Sequential Reads: 560 MB/s, Sequential Writes: 530 MB/s, Max Random 4k: Read: 98,000 IOPS / Write: 88,000 IOPS, 7mm, 512MB Cache, Samsung MKX controller, V-NAND 3bit MLC	
2,3		SSD 250 Gb	M.2 NVMe SSD 250GB Samsung SSD 980	China	Samsung	250Gb m.2 2280,V-NAND 3bit MLC	M.2 NVMe SSD 250GB Samsung SSD 980, PCIe3.0 x4 / NVMe1.4, M2 Type 2280 form factor, Seq. Read: 2900 MB/s, Seq. Write: 1300 MB/s, Max Random 4k: Read /Write: 230K/320K IOPS, Samsung Pablo Controller, 512MB LPDDR4, V-NAND 3-bit MLC	

Lot 4 Stic de memorie USB

4,1		Stic de memorie 32 GB	Kingston DTKN/64GB	China	Kingston	32 GB, min USB 3.1, min R/W 90/40 MB/S	64GB USB3.2 Kingston DataTraveler Kyson Silver, Metal casing, Compact and lightweight (Read 200 MByte/s)	
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4,2	30237000-9	Stic de memorie 64 Gb	Kingston DTKN/64GB	China	Kingston	64 GB, min USB 3.1, min R/W 110/40 MB/S	64GB USB3.2 Kingston DataTraveler Kyson Silver, Metal casing, Compact and lightweight (Read 200 MByte/s)	
4,3		Stic de memorie128 Gb	Kingston DTKN/128GB	China	Kingston	128 GB, min,: USB 3,1, min:R/W 200/60 MB/s	128GB USB3.2 Kingston DataTraveler Kyson Silver, Metal casing, Compact and lightweight (Read 200 MByte/s, Write 60 MByte/s)	
Loot nr 3								
		Total						

Valabilitatea ofertei : 30 de zile

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Data: 23.05.2024